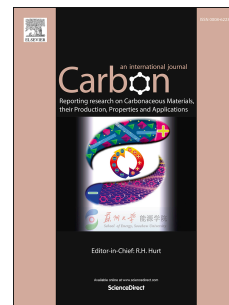


Accepted Manuscript

Nitrogen ion implanted ultrananocrystalline diamond films: A better electrostatic charge storage medium

Kalpataru Panda, Jae-Eun Kim, Jeong Young Park



PII: S0008-6223(18)30868-6

DOI: [10.1016/j.carbon.2018.09.052](https://doi.org/10.1016/j.carbon.2018.09.052)

Reference: CARBON 13480

To appear in: *Carbon*

Received Date: 5 July 2018

Revised Date: 12 September 2018

Accepted Date: 16 September 2018

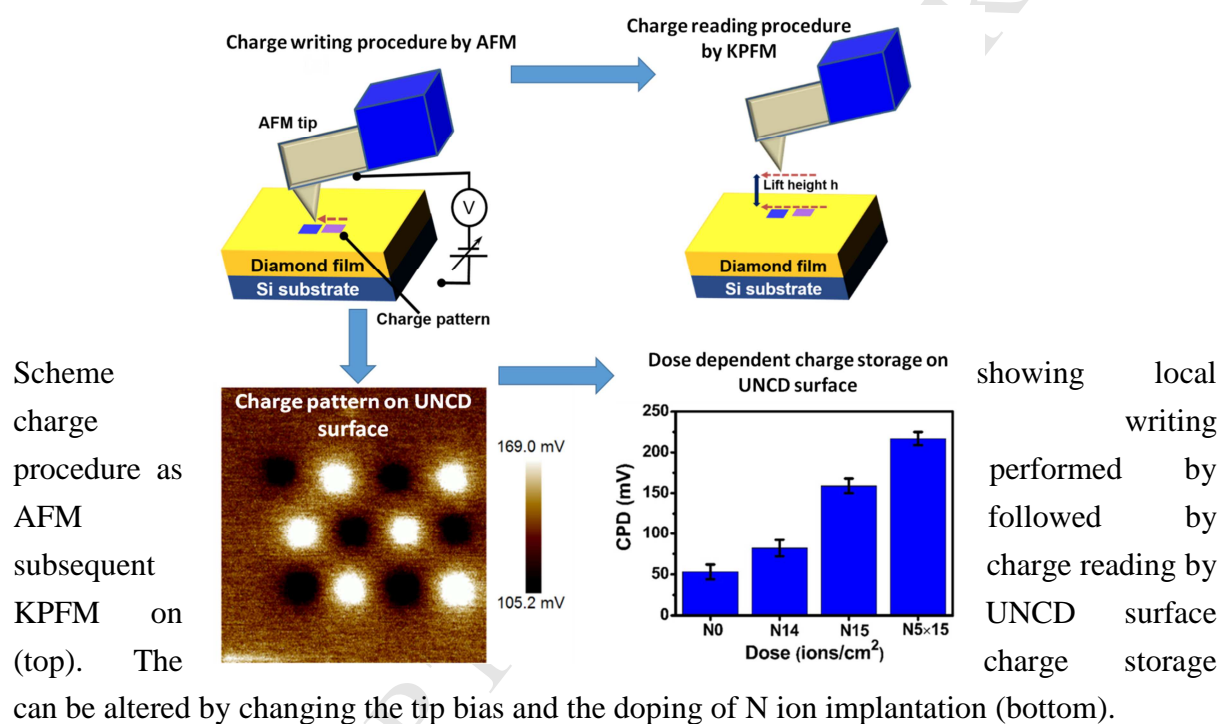
Please cite this article as: K. Panda, J.-E. Kim, J.Y. Park, Nitrogen ion implanted ultrananocrystalline diamond films: A better electrostatic charge storage medium, *Carbon* (2018), doi: <https://doi.org/10.1016/j.carbon.2018.09.052>.

This is a PDF file of an unedited manuscript that has been accepted for publication. As a service to our customers we are providing this early version of the manuscript. The manuscript will undergo copyediting, typesetting, and review of the resulting proof before it is published in its final form. Please note that during the production process errors may be discovered which could affect the content, and all legal disclaimers that apply to the journal pertain.

Graphical Abstract

Nitrogen Ion Implanted Ultrananocrystalline Diamond Films: A Better Electrostatic charge Storage Medium

Kalpataru Panda, Jae-Eun Kim, Jeong Young Park



Download English Version:

<https://daneshyari.com/en/article/10155169>

Download Persian Version:

<https://daneshyari.com/article/10155169>

[Daneshyari.com](https://daneshyari.com)